

Features

- Excellent DC specifications
 - ◆ **Small voltage offset: $\pm 50\mu\text{V}$ (MAX)**
 - ◆ **Small voltage offset drift: $0.2\mu\text{V}/^\circ\text{C}$ (MAX)**
 - ◆ **Small input bias current: 1.5nA (MAX)**
- Excellent AC specifications
 - ◆ **CMRR: 80dB @ G=1 (MIN)**
 - ◆ **Small input noise: $15\text{nV}/\sqrt{\text{Hz}}$ @ G=10**
 - ◆ **Input noise (0.1 Hz to 10 Hz): $1\mu\text{V}$ p-p**
 - ◆ **-3dB Bandwidth: 1.6MHz**
 - ◆ **Slew rate: 5V/us**
- Gain set with 1 external resistor (gain range 1 to 1,000)
- SUPPLY VOLTAGE: **$\pm 2\text{V}$ to $\pm 18\text{V}$**
- RAIL to RAIL for VOLTAGE OUTPUT
- Operating Temperature: -45°C to $+125^\circ\text{C}$
- SOP8, MSOP8 & DFN3X3-8 PACKAGE

Applications

- Weigh scales for bridge amplifiers
- Medical and ECG Amplifiers
- Industrial Process Control
- Precision data acquisition system
- Pressure sensors
- Precision current measurement

Description

The TPA1286 is a low cost, wide supply range instrumentation amplifier that requires only one external resistor to set any gain between 1 and 1,000. The TPA1286 is designed to work with a variety of single voltages. A wide input range and rail-to-rail output allow the signal to make full use of the supply rails. Low voltage offset, low offset drift, low gain drift, high gain accuracy, and high CMRR make this part an excellent choice in applications that demand the best DC performance.

The TPA1286 operates from single 4V to 36V supply, offers breakthrough performance throughout the -40°C to $+125^\circ\text{C}$ temperature range. It features a zero-drift core, which leads to a typical offset drift of $0.2\mu\text{V}/^\circ\text{C}$ throughout the operating temperature range.

TPA1286 is available in SOP8, MSOP8 and DFN3X3-8 package

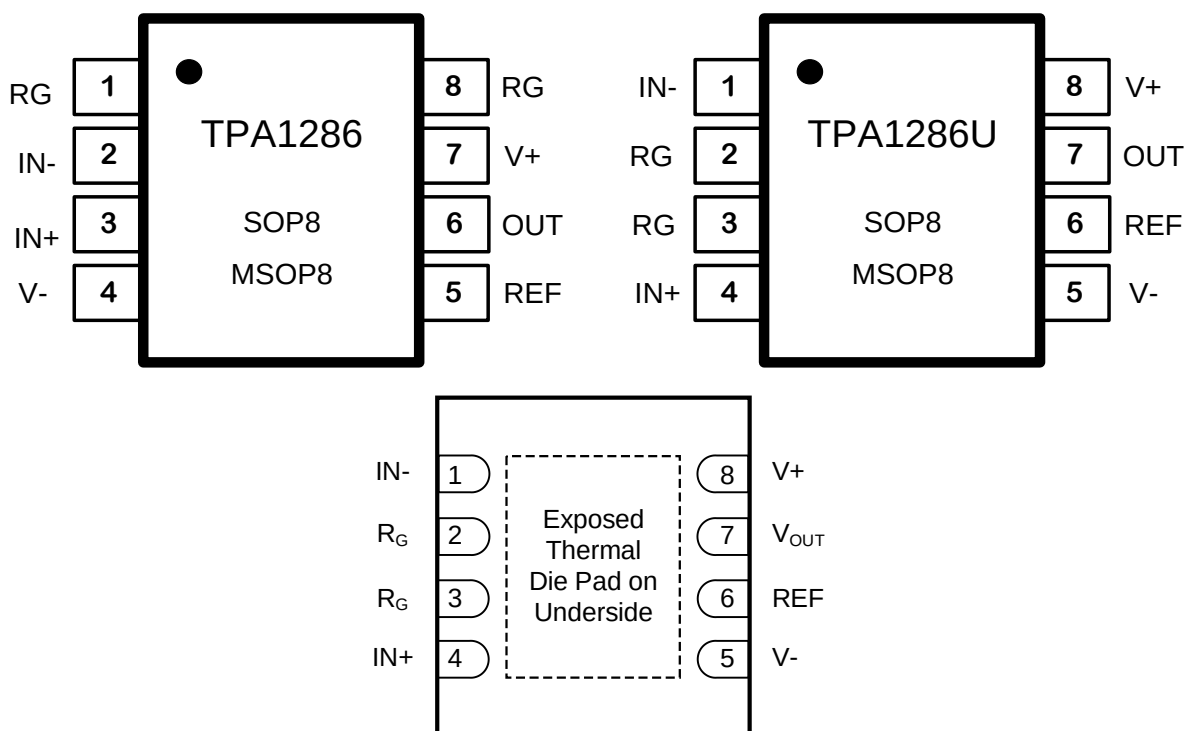
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Revision History

Date	Revision	Notes
2020/2/5	Rev.Pre.0	Initial Version
2020/12/25	Rev.A.0	Released version
2021/3/30	Rev.A.1	Add DFN3X3-8 package
2022//5/1	Rev.A.2	Update package outline dimensions

Pin Configuration



PIN NAME	TPA1286 DESCRIPTION
IN-	Negative Input
IN+	Positive Input.
RG	Gain setting
VREF	Reference Input.
OUT	Output
V+	Positive power supply
V-	Negative power supply
Thermal pad	Exposed thermal die pad is internally connected to -Vs. Connect externally to -Vs or leave floating.

Order Information

Model Name	Order Number	Package	Transport Media, Quantity	Package Marking
TPA1286	TPA1286-SO1R	8-Pin SOP8	Tape and Reel, 4,000	1286
	TPA1286U-SO1R	8-Pin SOP8	Tape and Reel, 4,000	1286U
	TPA1286-VS1R	8-Pin MSOP8	Tape and Reel, 3,000	1286
	TPA1286U-VS1R	8-Pin MSOP8	Tape and Reel, 3,000	1286U
	TPA1286U-DF7R	8-Pin DFN3X3	Tape and Reel, 4,000	286U

Absolute Maximum Ratings ^{Note 1}

Supply Voltage40V

Input Voltage.....(V-) – 0.3 to (V+) + 0.3V

Differential Input Voltage (V+) – (V-)

Input Current: IN+, IN- ^{Note 2}±10mA

Operating Temperature Range.....–40°C to 125°C

Maximum Working Junction Temperature..... 150°C

Storage Temperature Range..... –65°C to 150°C

Lead Temperature (Soldering, 10 sec)260°C

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: The inputs are protected by ESD protection diodes to power supply.

ESD, Electrostatic Discharge Protection

Symbol	Parameter	Condition	Minimum Level	Unit
HBM	Human Body Model ESD	ANSI/ESDA/JEDEC JS-001	3	kV
CDM	Charged Device Model ESD	ANSI/ESDA/JEDEC JS-002	1.5	kV

Thermal Resistance

Package Type	θ_{JA}	θ_{JC}	Unit
8-Pin SOP8	158	43	°C/W
8-Pin MSOP8	210	45	°C/W
DFN3X3-8	51	60	°C/W

Electrical Characteristics

The specifications are at TA = 25°C, V+ = +15V, V- = -15V, REF = 0V, unless otherwise noted

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
INPUT						
V _{OSI}	Input Stage Offset Voltage	At RTI		±10	±50	μV
		At RTI, -40°C to 125°C		±0.1	±0.2	μV/°C
V _{OSO}	Output Stage Offset Voltage	At RTI		±100	±300	μV
		At RTI, -40°C to 125°C		±0.2	±0.3	μV/°C
V _{OS}	Offset Voltage	At RTI		±10 ±100/G	±50 ±300/G	μV
V _{OS} TC	Input Offset Voltage Drift	-40°C to 125°C			±0.2 ±0.3/G	μV/°C
V _{CM}	Common-mode Input Range	-40°C to 125°C	(V-) +0.1		(V+) - 1.5	V
CMRR	Common Mode Rejection Ratio	CMRR at DC, G=1	80	100		dB
		CMRR at DC, G=10	100	120		dB
		CMRR at DC, G=100	110	130		
		CMRR at DC, G=1000	120	140		
I _B	Input Bias Current			0.3	1.5	nA
		-40°C to 125°C		10		pA/°C
I _{OS}	Input Offset Current			0.3	1.5	nA
		-40°C to 125°C		10		pA/°C
Input impedance	Input impedance	Differential		57 6		GΩ pF
		Common mode		44 14		GΩ pF
PSRR	Power Supply Rejection Ratio	G=1	100	120		dB
		G=10	110	130		dB
		G=100	120	138		dB
		G=1000	130	140		dB
RIN	Reference input			20		kΩ
NOISE RTI						
e _n	Input Voltage Noise Density	f = 1kHz, G=10		15		nV/√Hz
		f = 0.1Hz to 10Hz, G=1		1		μV p-p
OUTPUT						
G	G = 1 + (49.4 kΩ/RG)		1		1000	V/V
GE	Gain Error	G=1		±0.01%	±0.05%	
		G=10		±0.1%	±0.15%	
		G=100		±0.1%	±0.2%	
		G=1000		±0.3%	±0.6%	
G TC	Gain Vs Temperature	-40°C to 125°C, G=1		1	5	ppm/°C

High Voltage, Precision, Zero-drift, Instrumentation Amplifier

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I _{SC}	Short circuit current	-40°C to 125°C		±70		mA
V _{OH}	Output Swing from Supply Rail	-40°C to 125°C, R _L = 10 kΩ		0.12	0.2	V
V _{OL}	Output Swing from Supply Rail	-40°C to 125°C, R _L = 10 kΩ		0.05	0.1	V
FREQUENCY RESPONSE						
BW	-3dB Bandwidth	G=1		1600		kHz
		G=10		400		kHz
		G=100		100		kHz
		G=1000		11		kHz
ST	Setting time to 0.01%	G=1		2.1		μs
SR	Slew Rate	G=1		5		V/μs
		G=100		2.5		V/μs
POWER SUPPLY						
V+	Supply Voltage		±2		±18	V
I _Q	Quiescent Current			3.8	4.5	mA
TEMPERATURE RANGE						
	Specified range		-40		125	°C

Typical Performance Characteristics

The TPA1286 is used for characteristics at $T_A = 25^\circ\text{C}$, $V_s = \pm 15\text{V}$, $R_L = 10\text{ k}\Omega$, unless otherwise noted.

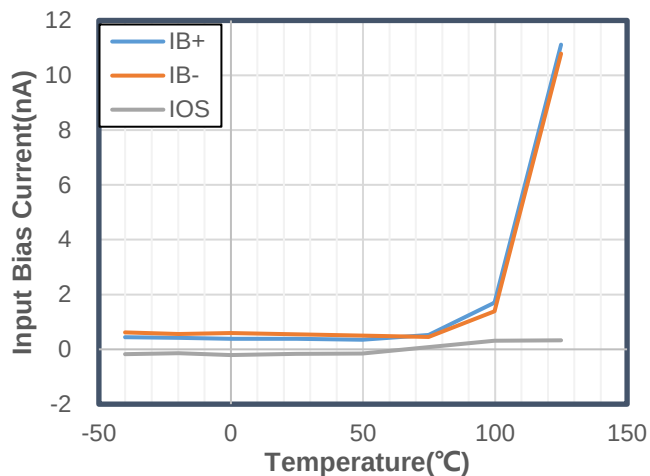


Figure 1 IB Vs. Temperature

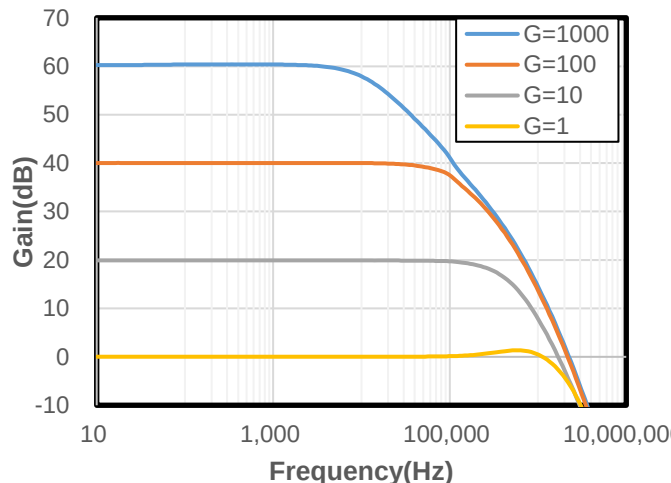


Figure 2 Gain Vs. Frequency

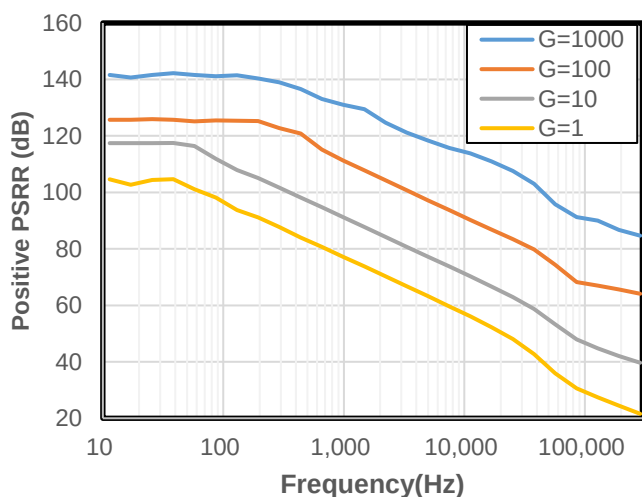


Figure 3 Positive PSRR Vs. Frequency

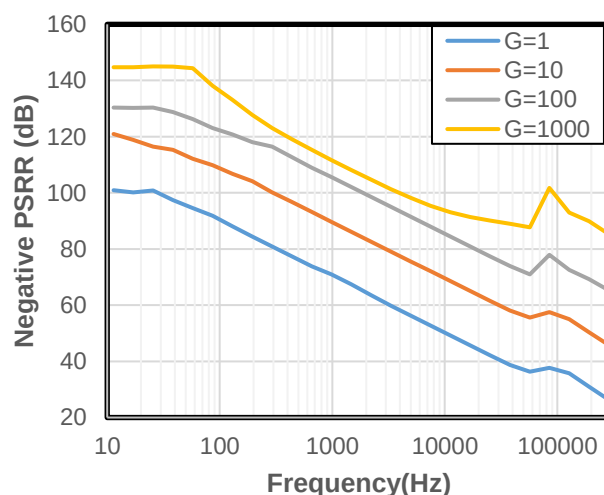


Figure 4 Negative PSRR Vs. Frequency

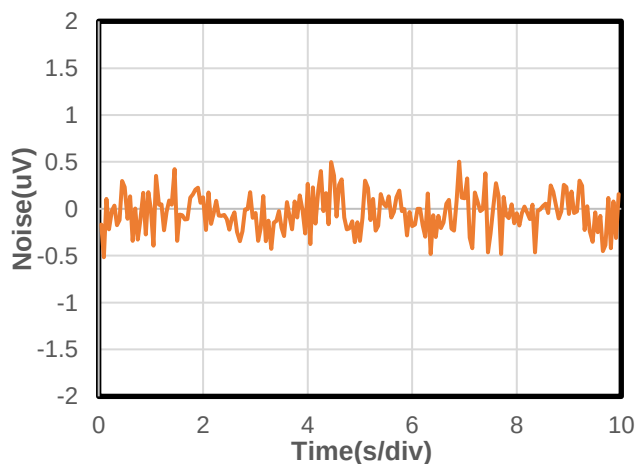


Figure 5 0.1Hz to 10Hz RTI Noise

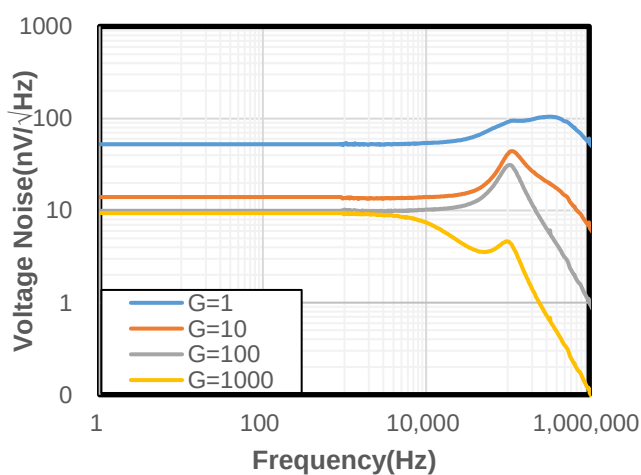


Figure 6 Noise Density Vs Frequency

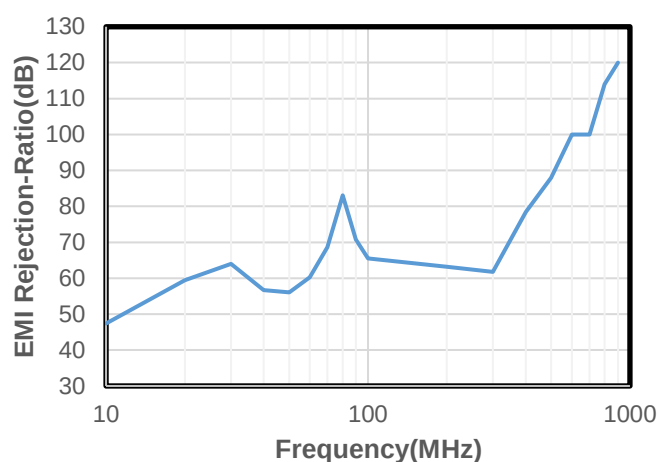


Figure 7 EMIRR

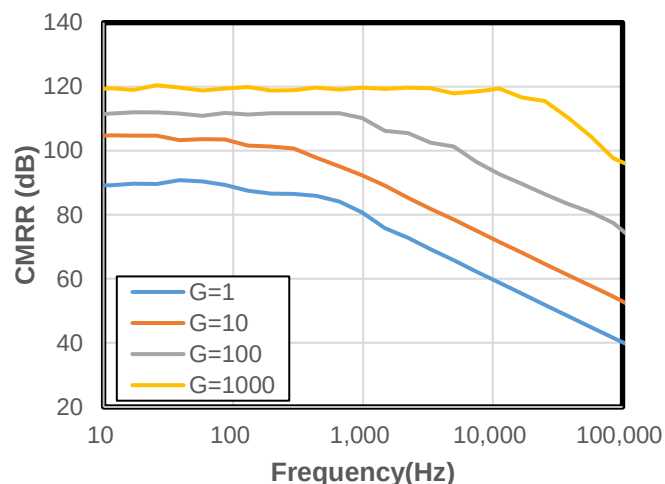


Figure 8 CMRR Vs. Frequency

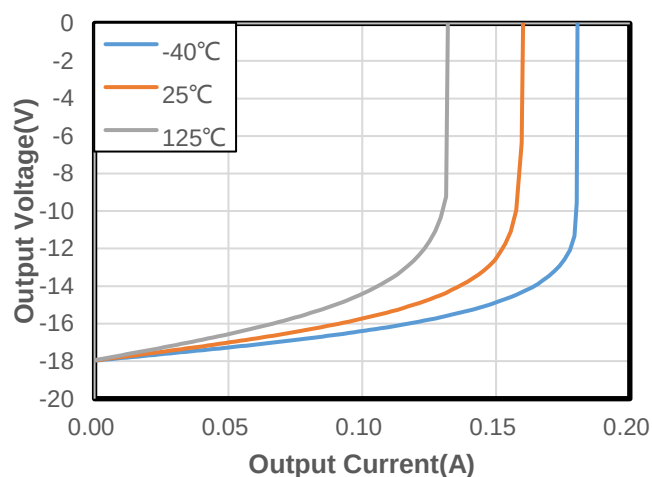


Figure 9 Negative Output Voltage Swing Vs. Output Current

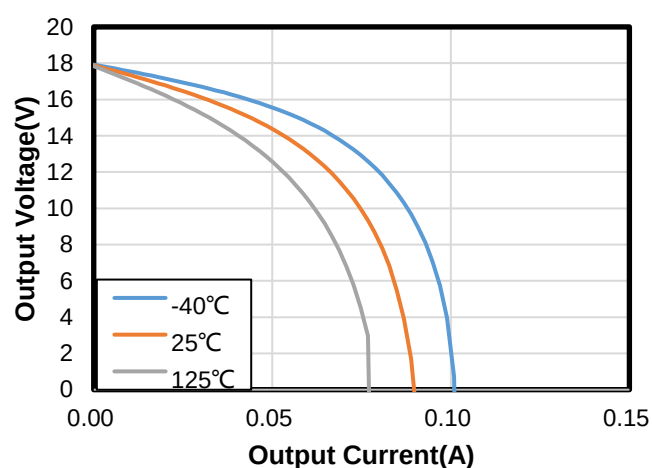


Figure 10 Positive Output Voltage Swing Vs. Output Current

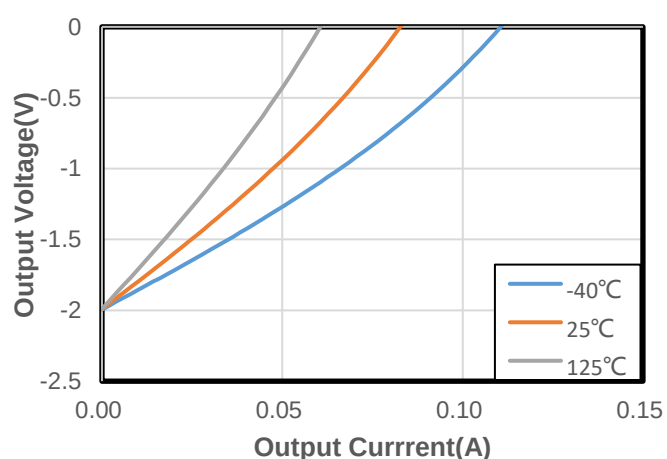


Figure 11 Negative Output Voltage Swing Vs. Output Current

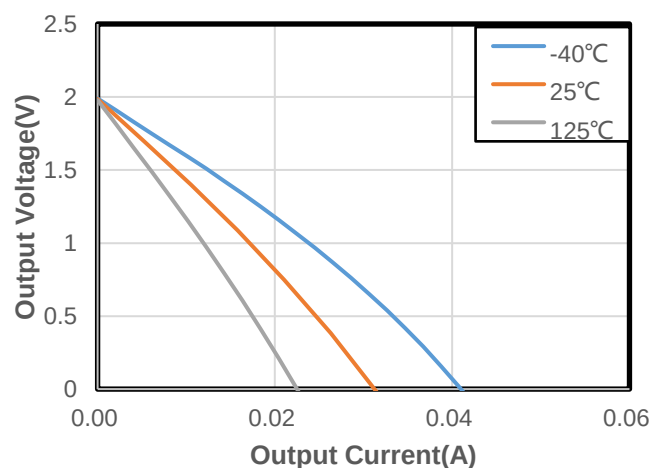


Figure 12 Positive Output Voltage Swing Vs. Output Current

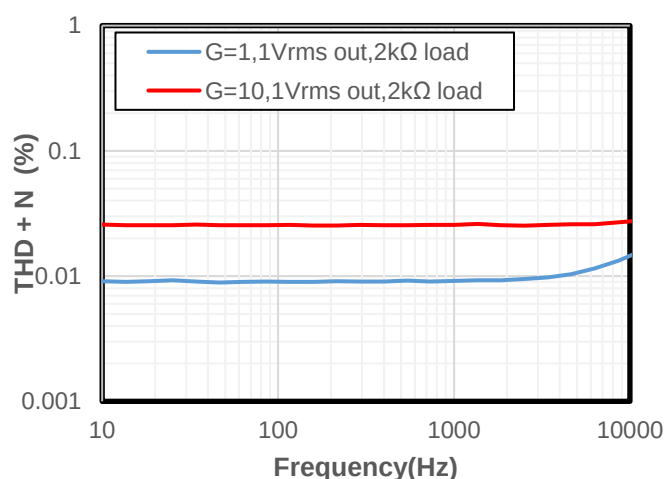


Figure 13 THD + N Vs. Frequency

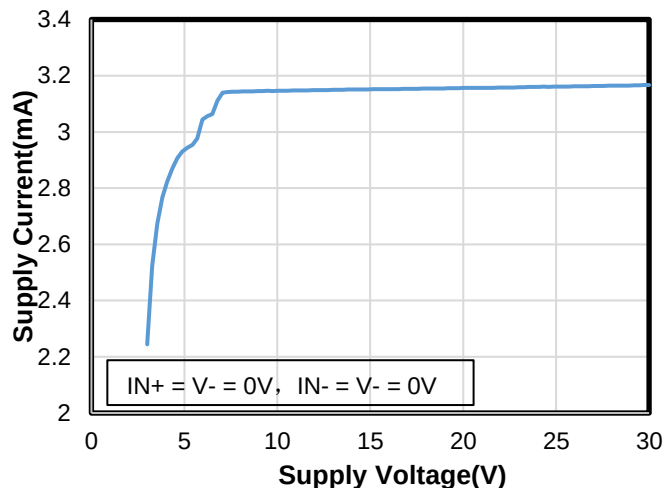


Figure 14 Supply Current Vs. Voltage

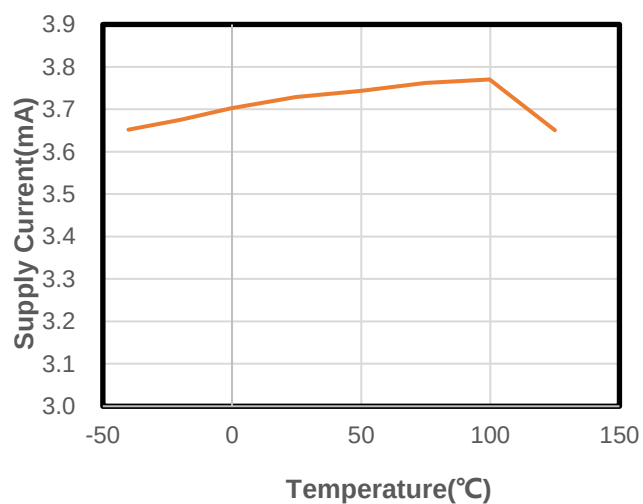


Figure15 Supply Current Vs. Temp

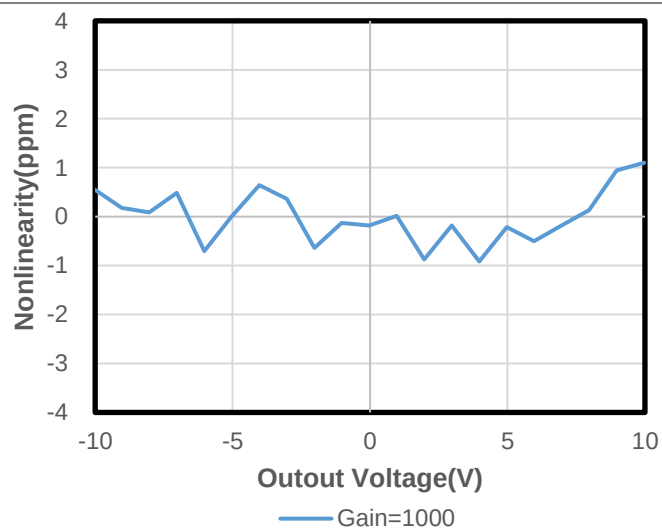


Figure 16 Gain Nonlinearity

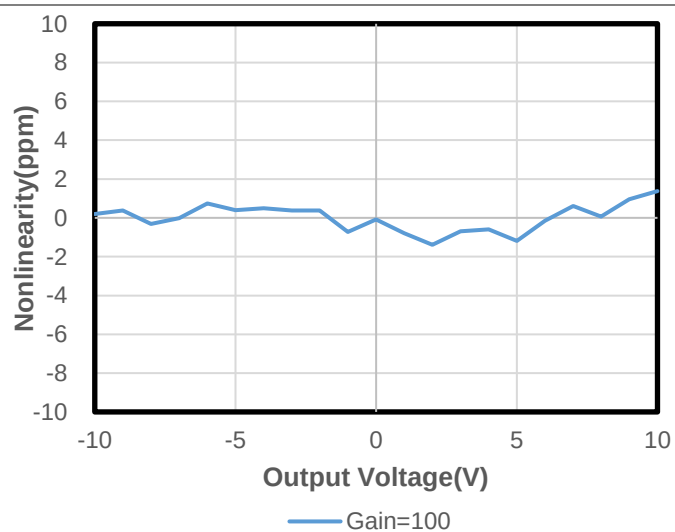


Figure 17 Gain Nonlinearity

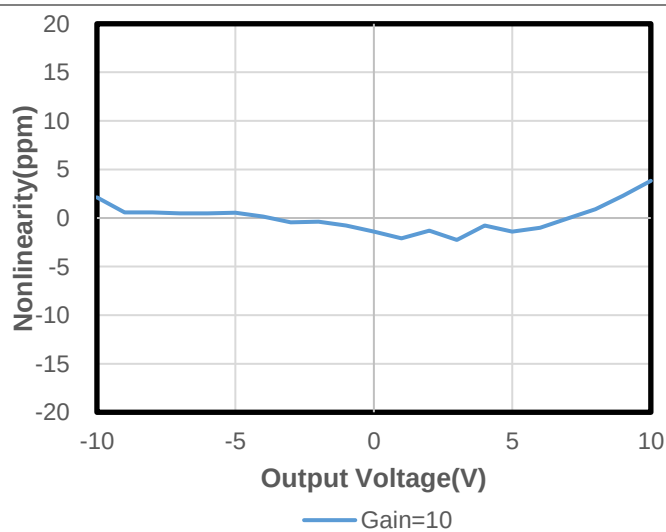
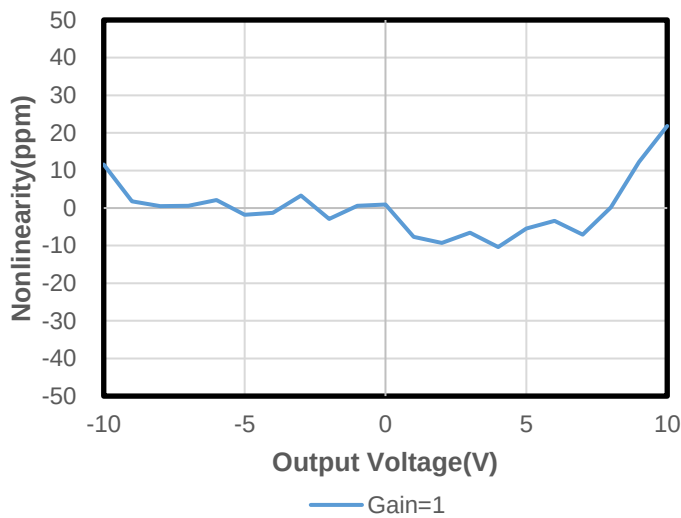


Figure 18 Gain Nonlinearity


Figure 19 Gain Nonlinearity


Voltage: 2V/div for Output, Time: 10us/div G=1, VREF = GND; VIN=10VPP, Load R=10K
Figure 20 Slew Rate



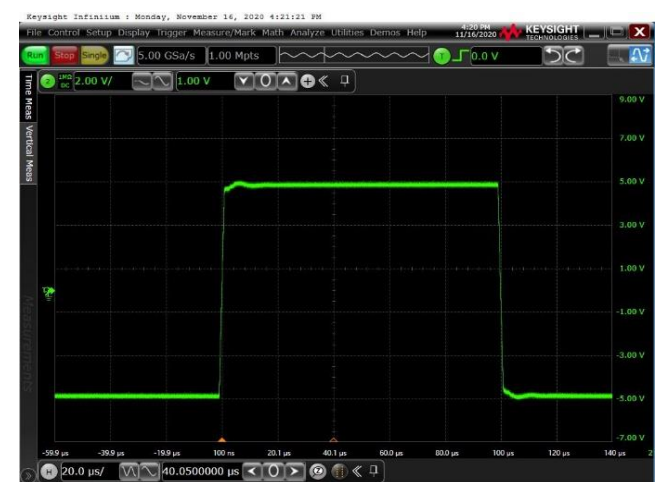
Voltage: 5V/div for Output, Time: 2us/div G=10, VREF = GND;
VIN=10VPP, Load R=10K C=100pF
Figure 21 Positive Overload Recovery



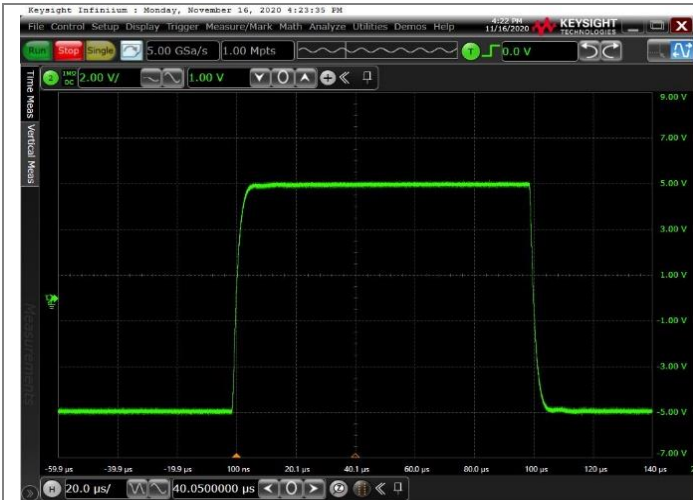
Voltage: 5V/div for Output, Time: 2us/div G=10, VREF = GND;
VIN=10VPP, Load R=10K C=100pF
Figure 22 Negative Overload Recovery



Voltage: 2V/div for Output, Time: 10us/div G=1, VREF = GND;
VIN=10VPP, Load R=10K C=100pF
Figure 23 Large-Signal Pulse Response



Voltage: 2V/div for Output, Time: 20us/div G=10, VREF = GND;
VIN=1VPP, Load R=10K C=100pF
Figure 24 Large-Signal Pulse Response



Voltage: 2V/div for Output, Time: 20us/div G=100, VREF = GND; VIN=0.1VPP, Load R=10K C=100pF

Figure 25 Large-Signal Pulse Response



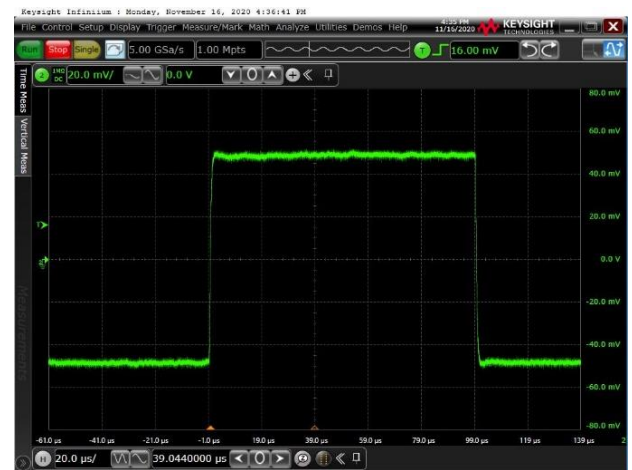
Voltage: 2V/div for Output, Time: 50us/div G=1000, VREF = GND; VIN=10mVPP, Load R=10K C=100pF

Figure 26 Large-Signal Pulse Response



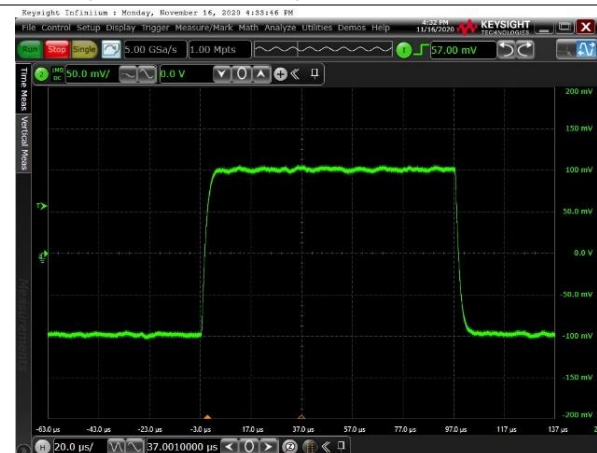
Voltage: 25mV/div for Output, Time: 10us/div G=1, VREF = GND; VIN=100mVPP, Load R=10K C=100pF

Figure 27 Small-Signal Pulse Response



Voltage: 20mV/div for Output, Time: 20us/div G=10, VREF = GND; VIN=10mVPP, Load R=10K C=100pF

Figure 28 Small-Signal Pulse Response



Voltage: 50mV/div for Output, Time: 20us/div G=100, VREF = GND; VIN=2mVPP, Load R=10K C=100pF

Figure 29 Small-Signal Pulse Response



Voltage: 500mV/div for Output, Time: 50us/div G=10, VREF = GND; VIN=2mVPP, Load R=10K C=100pF

Figure 30 Small-Signal Pulse Response

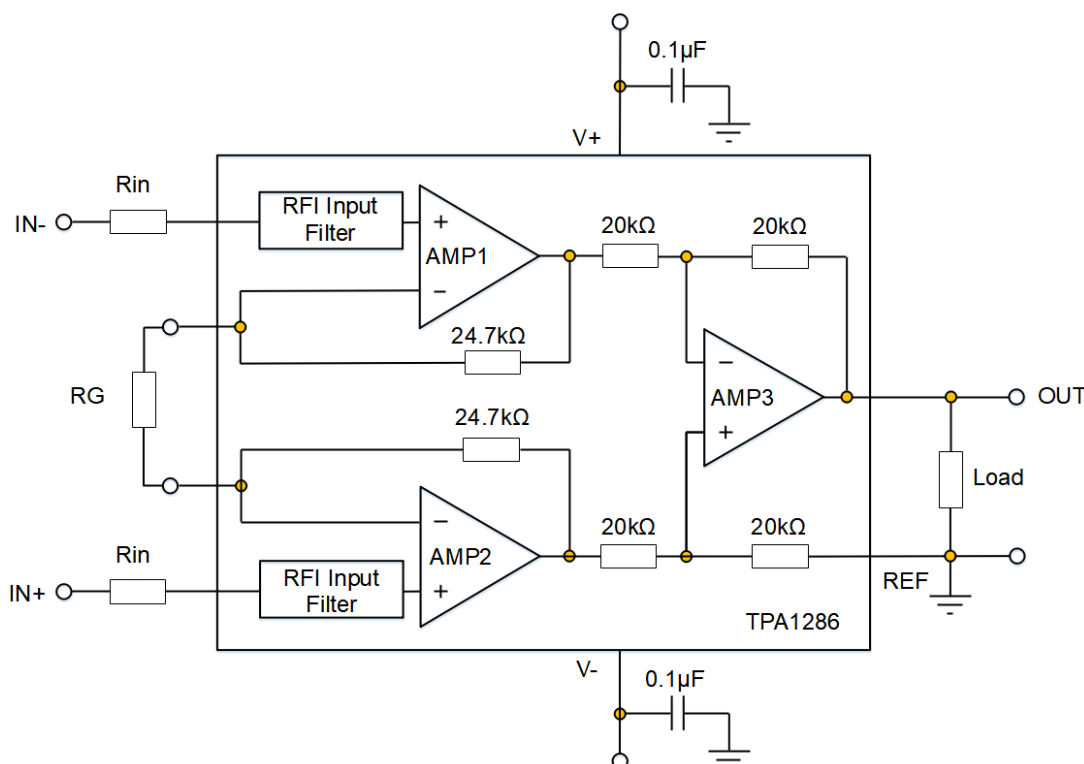
Operation Overview

The TPA1286 is a monolithic instrumentation amplifier (INA) based on the high voltage, precision zero-drift OPA core, and classic 3-op amp topology. The TPA1286 also integrates precision resistors to ensure excellent common mode rejection and low gain error. The combination of the zero-drift amplifier core and the precision resistors allows this device to achieve outstanding dc precision and makes the TPA1286 ideal for many high-voltage industrial applications.

A unique pinout of the TPA1286U enable to meet a good CMRR specification. The balanced pinout reduces the parasitic that had adversely affected CMRR performance. In addition, this pinout simplifies board layout because associated traces are grouped together. For example, the gain setting resistor pins are adjacent to the inputs, and the reference pin is next to the output.

Applications Information

TPA1286 Application block diagram



Selecting GAIN Resistor

The gain of the TPA1286 is set by a single external resistor, RG, connected between RG pins. The value of RG is selected according to below Equation. TPA1286 can be set as G = 1 when no gain resistor is used. Gain accuracy is determined by the accuracy of RG. The stability and temperature drift of the external gain setting resistor, RG, also affects gain. The contribution of RG to gain accuracy and drift can be determined from below equation.

$$G = 1 + \frac{49.4k}{RG}$$

REFERENCE INPUT PIN

As shown in above Figure, the reference pin, REF, is connected with a 20 k Ω resistor. The output of the instrumentation amplifier is referenced to the voltage on the REF pin; this is useful when the output signal needs to be offset to a precise mid-supply level. For example, a voltage source can be tied to the REF pin to level-shift the output so that the TPA1286 can interface with an ADC. For best performance, source impedance to the REF pin should be kept as low as possible, because parasitic resistance can adversely affect CMRR and gain accuracy. PCB Layout should be very careful to tie REF to the appropriate local cleaning ground.

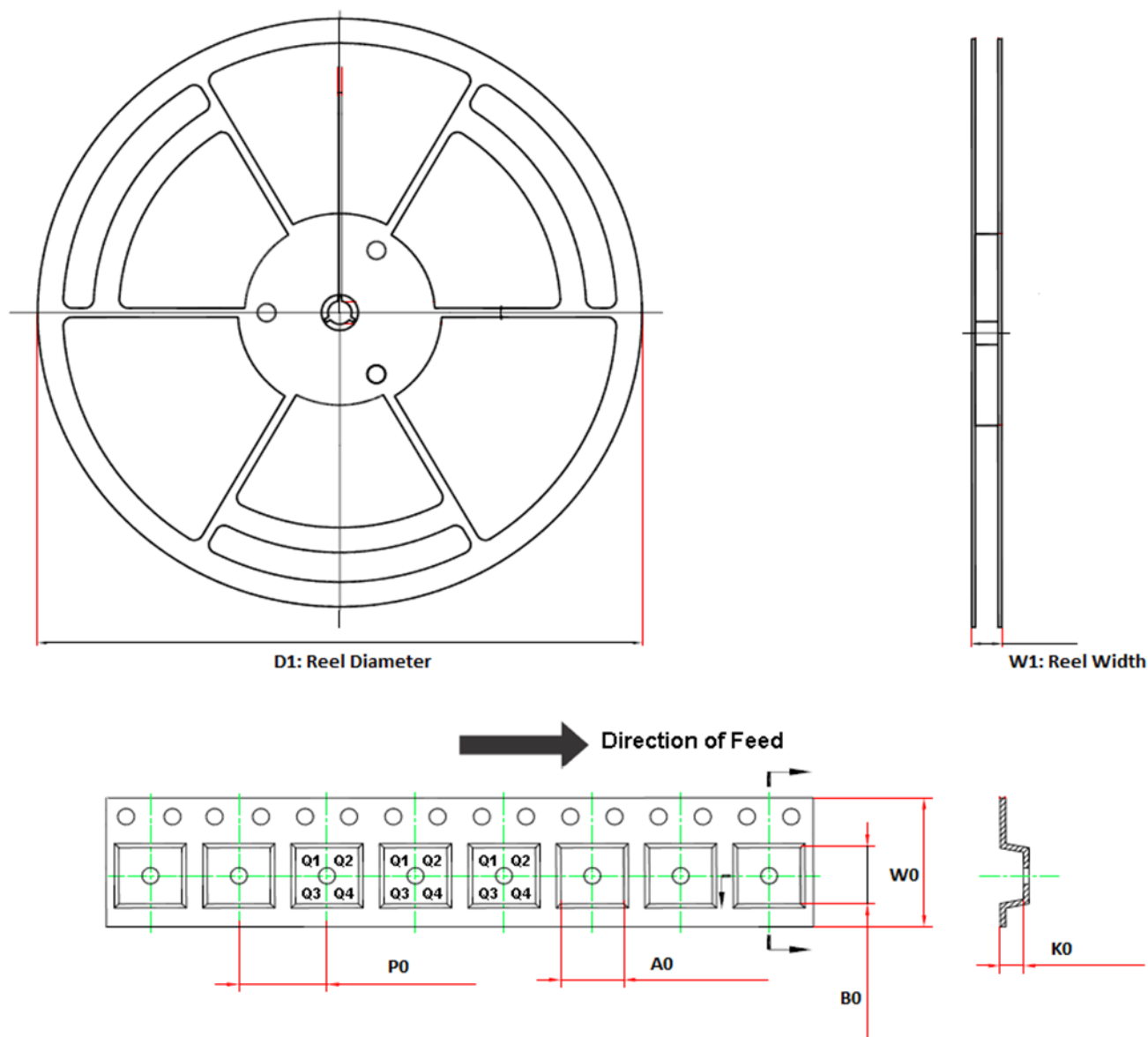
Power Supply Recommendation

A stable and cleaning dc voltage should be used to be as power supply of the instrumentation amplifier, which noise on the supply pins can affect performance. Bypass capacitors should be used to decouple the amplifier. A 0.1 μ F capacitor should be placed close to each supply pin.

Proper Board Layout

To maximizes system performance, careful board layout is needed. Traces from the gain setting resistor to the RG pins should be kept as short as possible to minimize parasitic inductance. To ensure the most accurate output, the trace from the REF pin should either be connected to the local ground of the TPA1286, or connected to a voltage that is referenced to the local ground of the TPA1286

TAPE AND REEL INFORMATION



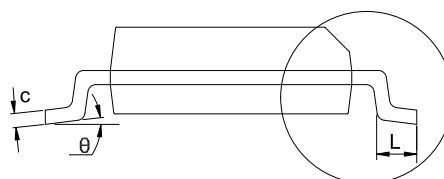
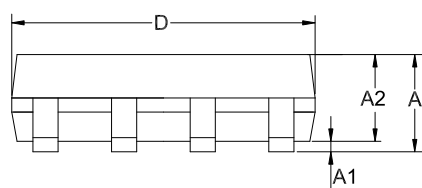
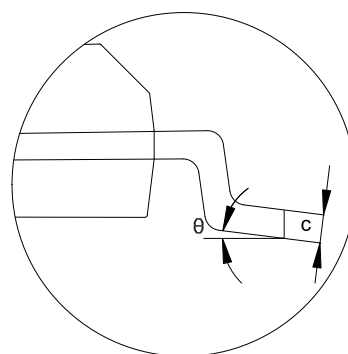
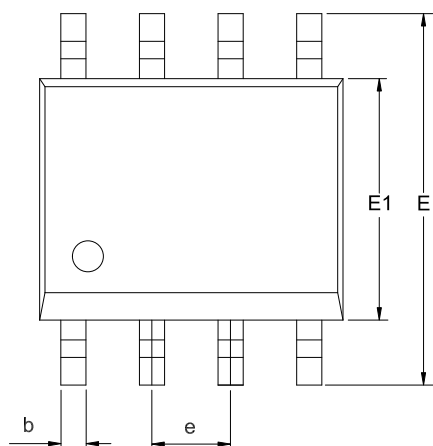
Order Number	Package	D1 (mm)	W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	W0 (mm)	Pin1 Quadrant
TPA1286-SO1R	8-Pin SOP	330.0	17.6	6.4	5.4	2.1	8.0	12.0	Q1
TPA1286U-SO1R	8-Pin SOP	330.0	17.6	6.4	5.4	2.1	8.0	12.0	Q1
TPA1286-VS1R	8-Pin MSOP	330.0	17.6	5.2	3.3	1.5	8.0	12.0	Q1
TPA1286U-VS1R	8-Pin MSOP	330.0	17.6	5.2	3.3	1.5	8.0	12.0	Q1
TPA1286U-DF7R	DFN3X3-8	330.0	16.8	3.3	3.3	1.1	8.0	12.0	Q2

Package Outline Dimensions

SOIC-8

Package Outline Dimensions

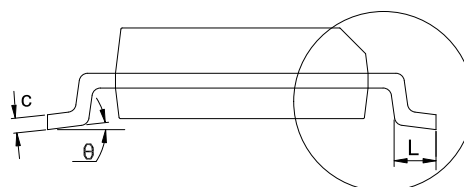
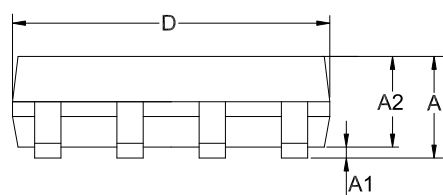
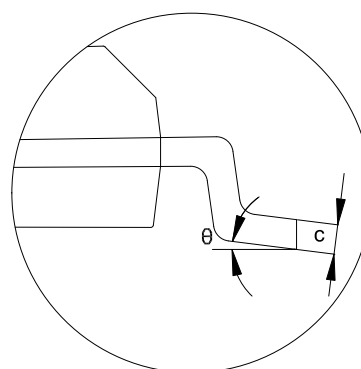
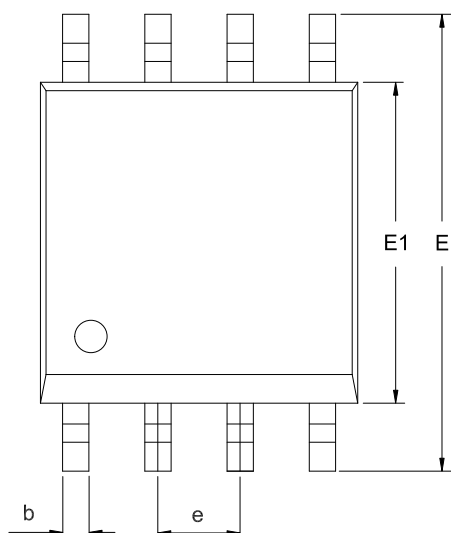
SO1(SOP-8-A)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	1.350	1.750	0.053	0.069
A1	0.050	0.250	0.002	0.010
A2	1.250	1.550	0.049	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.007	0.010
D	4.700	5.100	0.185	0.201
E	5.800	6.200	0.228	0.244
E1	3.800	4.000	0.150	0.157
e	1.270 BSC		0.050 BSC	
L	0.400	1.000	0.016	0.039
θ	0	8°	0	8°

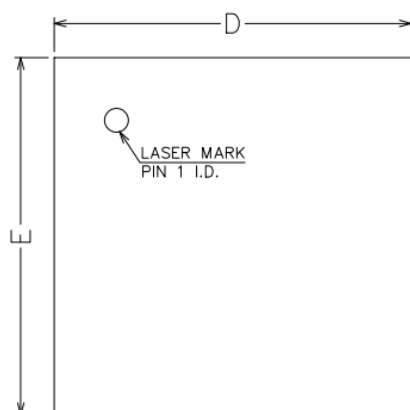
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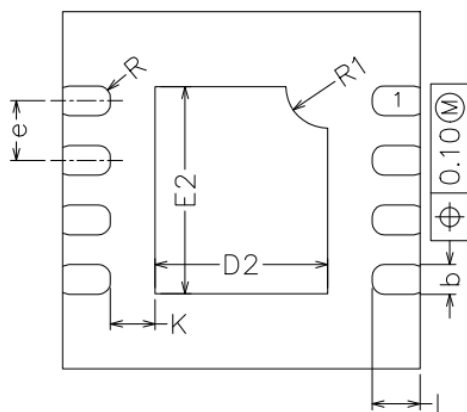
1. Do not include mold flash or protrusion.
2. This drawing is subject to change without notice.

MSOP8
Package Outline Dimensions
VS1(MSOP-8-A)

NOTES

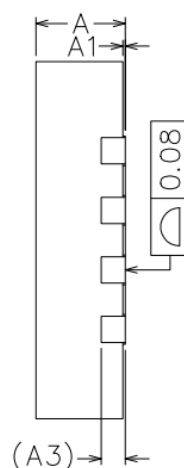
1. Do not include mold flash or protrusion.
2. This drawing is subject to change without notice.

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	0.800	1.100	0.031	0.043
A1	0.050	0.150	0.002	0.006
A2	0.750	0.950	0.030	0.037
b	0.250	0.380	0.010	0.015
c	0.090	0.230	0.004	0.009
D	2.900	3.100	0.114	0.122
E	4.700	5.100	0.185	0.201
E1	2.900	3.100	0.114	0.122
e	0.650 BSC		0.026 BSC	
L	0.400	0.800	0.016	0.031
θ	0	8°	0	8°

DFN3X3-8
Package Outline Dimensions
DF7(DFN3X3-8-D)

TOP VIEW

SIDE VIEW

BOTTOM VIEW
NOTES

1. Do not include mold flash or protrusion.
2. This drawing is subject to change without notice.


SIDE VIEW

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	0.700	0.800	0.028	0.031
A1	0.000	0.050	0.000	0.002
b	0.200	0.300	0.008	0.012
A3	0.150	0.250	0.006	0.010
D	2.900	3.100	0.114	0.122
D2	1.350	1.550	0.053	0.061
E	2.900	3.100	0.114	0.122
E2	1.640	1.840	0.065	0.072
e	0.500 BSC		0.020 BSC	
L	0.300	0.500	0.012	0.020